1 General description

NPN general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

PNP complements: BCW68F/G/H

2 Features and benefits

High current

AEC-Q101 qualified

3 Applications

· General-purpose switching and amplification

4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base		-	-	45	V
I _C	collector current			-	-	800	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	1	Α
h _{FE}	DC current gain	V_{CE} = 1 V; I_{C} = 100 mA; T_{amb} = 25 °C	[1]				
	BCW66F			100	-	250	
	BCW66G			160	-	400	
	BCW66H			250	-	600	

[1] pulsed: $t_p \le 300 \mu s$, $\delta \le 0.02$



5 Pinning information

Table 2. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base		
2	E	emitter	3	C
3	С	collector		BE sym123

6 Ordering information

Table 3. Ordering information

Table of Grading Information					
Type number	Package				
	Name	Description	Version		
BCW66F	TO-236AB	plastic surface-mounted package; 3 leads	SOT23		
BCW66G					
BCW66H					

7 Marking

Table 4. Marking

Table 4. Marking						
Ty	ype number		Marking code			
В	CW66F	[1]	EQ%			
В	CW66G	[1]	ER%			
В	CW66H	[1]	ES%			

^{[1] % =} placeholder for manufacturing site code

8 Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	50	V
V_{CEO}	collector-emitter voltage	open base	-	45	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current		-	800	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	1	Α
I _B	base current		-	100	mA

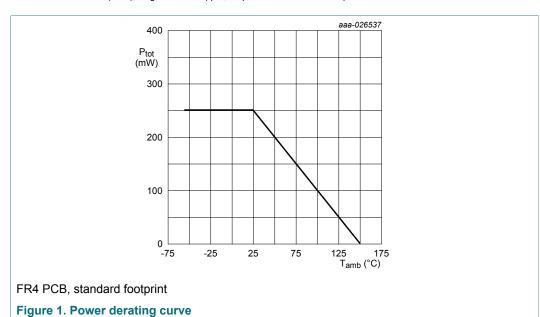
BCW66x_SER

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Symbol	Parameter	Conditions	Min	Max	Unit
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms	-	200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$ [1]	-	250	mW
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	150	°C
T _{stg}	storage temperature		-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB), single-sided chopper, tin-plated and standard footprint.

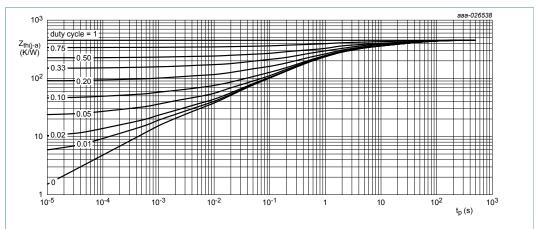


9 Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air [1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



FR4 PCB, standard footprint

Figure 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10 Electrical characteristics

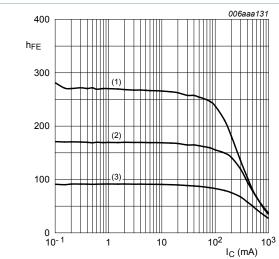
Table 7. Electrical characteristics

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base	V _{CB} = 40 V; I _E = 0 A		-	-	20	nA
	cut-off current	V _{CB} = 40 V; I _E = 0 A; T _j = 150 °C		-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A		-	-	20	nA
h _{FE}	DC current gain						
	BCW66F/G/H	V _{CE} = 1 V; I _C = 100 μA		75	-	-	
	BCW66F/G/H	V _{CE} = 1 V; I _C = 1 mA		75	-	-	
	BCW66F/G/H	V _{CE} = 1 V; I _C = 10 mA		75	-	-	
	BCW66F	V _{CE} = 1 V; I _C = 100 mA	[1]	100	-	250	
	BCW66G		[1]	160	-	400	
	BCW66H		[1]	250	-	630	
	BCW66F/G/H	V _{CE} = 1 V; I _C = 500 mA	[1]	40	-	-	
V _{CEsat}	collector-emitter	I _C = 100 mA; I _B = 10 mA	[1]	-	-	350	mV
	saturation voltage	I _C = 500 mA; I _B = 50 mA	[1]	-	-	450	mV
V _{BEsat}	base-emitter	I _C = 100 mA; I _B = 10 mA	[1]	-	-	1.25	V
	saturation voltage	I _C = 500 mA; I _B = 50 mA	[1]	-	-	1.25	V
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 10 mA; f = 100 MHz		100	-	-	MHz
C _c	collector capacitance	V _{CB} = 10 V; I _E = i _e = 0 A; f = 1 MHz		-	3	-	pF

^[1] pulsed; $t_p \le 300 \mu s$; $\delta \le 0.02$

Table 8.



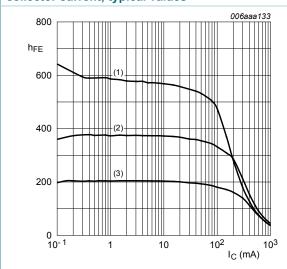
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Figure 3. BCW66F: DC current gain as a function of collector current; typical values



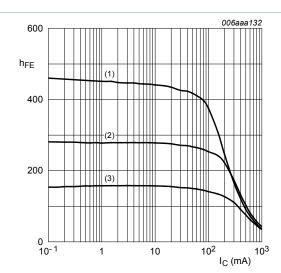
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = -55 °C$$

Figure 5. BCW66H: DC current gain as a function of collector current; typical values



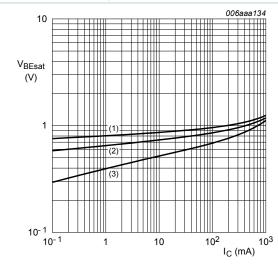
$$V_{CE} = 1 V$$

$$(1)_{amb} = 150 \, ^{\circ}C$$

(2)
$$_{amb}$$
 = 25 $^{\circ}C$

(3)
$$_{amb}$$
 = -55 $^{\circ}$ C

Figure 4. BCW66G: DC current gain as a function of collector current; typical values

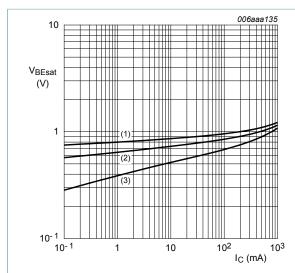


$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55 \,^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Figure 6. BCW66F: Base-emitter saturation voltage as a function of collector current; typical values

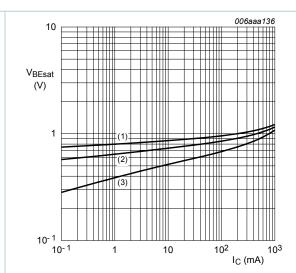


$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$



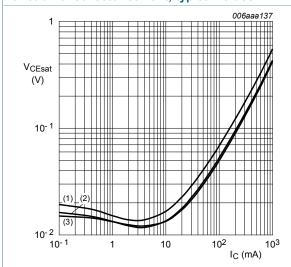
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55$$
 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Figure 7. BCW66G: Base-emitter saturation voltage as a function of collector current; typical values

Figure 8. BCW66H: Base-emitter saturation voltage as a function of collector current; typical values



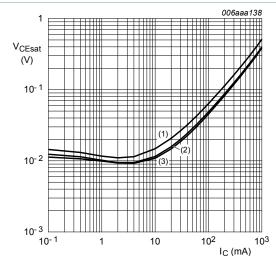
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Figure 9. BCW66F: Collector-emitter saturation voltage as a function of collector current; typical values



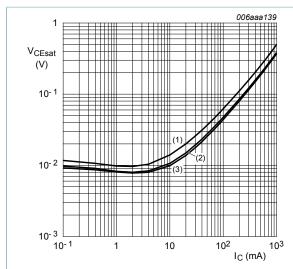
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Figure 10. BCW66G: Collector-emitter saturation voltage as a function of collector current; typical values



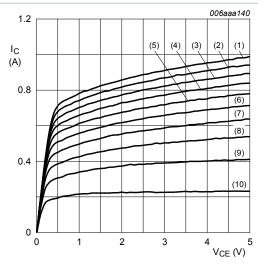
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb}$$
 = 150 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb}$$
 = -55 °C

Figure 11. BCW66H: Collector-emitter saturation voltage as a function of collector current; typical values



 T_{amb} = 25 °C

(1) $I_B = 16.0 \text{ mA}$

(2) $I_B = 14.4 \text{ mA}$

(3) $I_B = 12.8 \text{ mA}$

(4) $I_B = 11.2 \text{ mA}$

(5) $I_B = 9.6 \text{ mA}$ (6) $I_B = 8.0 \text{ mA}$

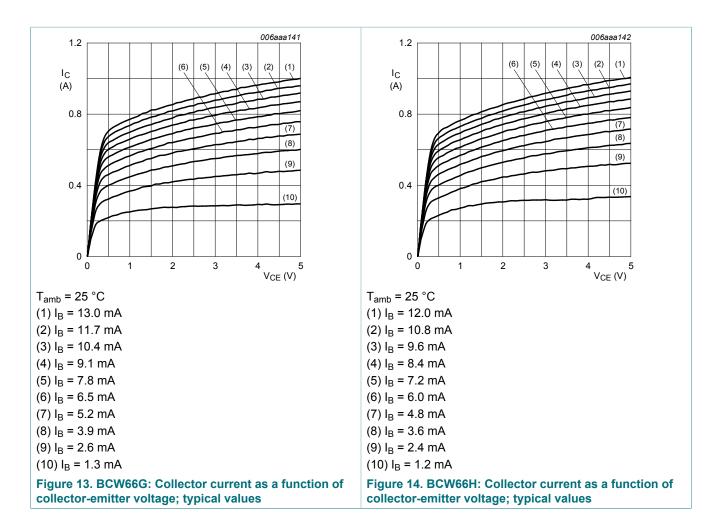
 $(7) I_B = 6.4 \text{ mA}$

(8) $I_B = 4.8 \text{ mA}$

(9) $I_B = 3.2 \text{ mA}$

 $(10) I_B = 1.6 mA$

Figure 12. BCW66F: Collector current as a function of collector-emitter voltage; typical values



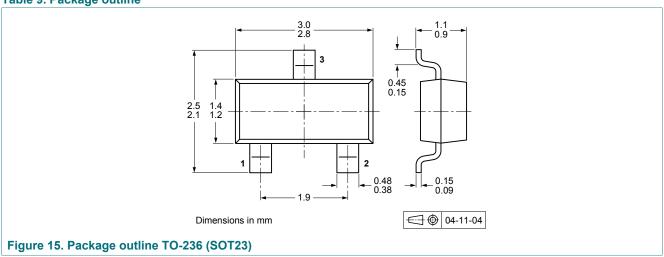
11 Test information

11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

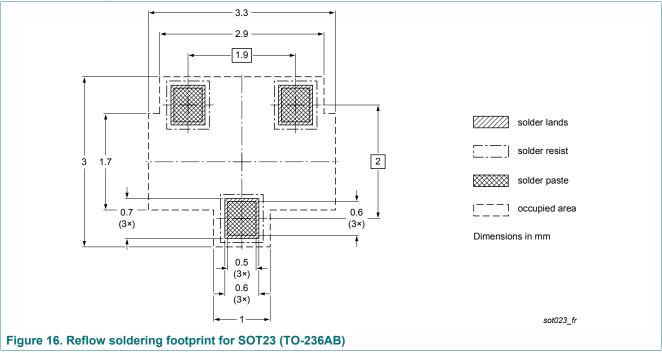
12 Package outline

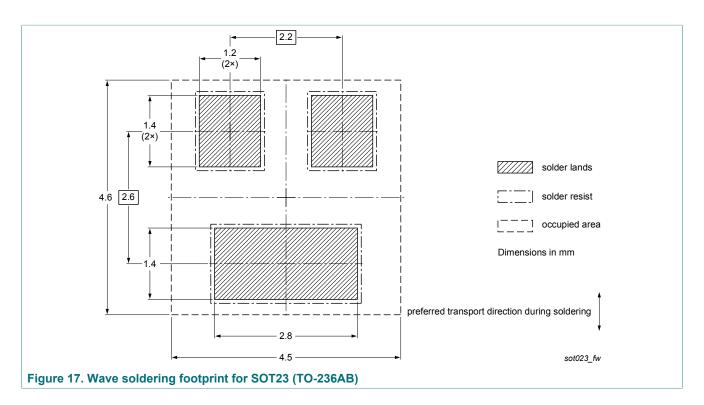
Table 9. Package outline



13 Soldering

Table 10. Soldering





14 Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BCW66x_SER v.1	21 April 2017	Product data sheet	-	-

15 Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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BCW66 series

45 V, 800 mA NPN general-purpose transistor

Tables

Tab. 1. Tab. 2.	Quick reference data1 Pinning2	Tab. 7. Tab. 8.	Electrical characteristics4
Tab. 3.	Ordering information2	Tab. 9.	Package outline9
Tab. 4.	Marking2	Tab. 10.	Soldering9
Tab. 5.	Limiting values2	Tab. 11.	Revision history10
Tab. 6.	Thermal characteristics		
Figur	es		
Fig. 1.	Power derating curve3	Fig. 9.	BCW66F: Collector-emitter saturation
Fig. 2.	Transient thermal impedance from junction to ambient as a function of pulse duration;		voltage as a function of collector current; typical values
	typical values4	Fig. 10.	BCW66G: Collector-emitter saturation
Fig. 3.	BCW66F: DC current gain as a function of	•	voltage as a function of collector current;
	collector current; typical values5		typical values6
Fig. 4.	BCW66G: DC current gain as a function of	Fig. 11.	BCW66H: Collector-emitter saturation
	collector current; typical values5		voltage as a function of collector current;
Fig. 5.	BCW66H: DC current gain as a function of		typical values7
	collector current; typical values5	Fig. 12.	BCW66F: Collector current as a function of
Fig. 6.	BCW66F: Base-emitter saturation voltage		collector-emitter voltage; typical values7
	as a function of collector current; typical	Fig. 13.	BCW66G: Collector current as a function of
	values5		collector-emitter voltage; typical values8
Fig. 7.	BCW66G: Base-emitter saturation voltage	Fig. 14.	BCW66H: Collector current as a function of
	as a function of collector current; typical	F: 45	collector-emitter voltage; typical values8
F: 0	values	Fig. 15.	Package outline TO-236 (SOT23)9
Fig. 8.	BCW66H: Base-emitter saturation voltage	Fig. 16.	Reflow soldering footprint for SOT23
	as a function of collector current; typical	Fig. 17	(TO-236AB)
	values6	Fig. 17.	Wave soldering footprint for SOT23 (TO-236AB)10
			(10 200/10)10

BCW66 series

45 V, 800 mA NPN general-purpose transistor

Contents

1	General description	1
2	Features and benefits	
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	
7	Marking	2
8	Limiting values	
9	Thermal characteristics	3
10	Electrical characteristics	4
11	Test information	8
11.1	Quality information	8
12	Package outline	
13	Soldering	
14	Revision history	
15	Legal information	

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